

DATA SHEET

74ALVT162241

2.5V/3.3V 16-bit buffer/driver with 30Ω
termination resistors (3-State)

Product specification
Supersedes data of 1997 Dec 16
IC23 Data Handbook

1998 Feb 13

2.5V/3.3V 16-bit buffer/driver with
30Ω termination resistors (3-State)

74ALVT162241

FEATURES

- 16-bit bus interface
- 5V I/O Compatible
- 3-State buffers
- Output capability: +12mA/-12mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Outputs include series resistance of 30Ω making external termination resistors unnecessary
- Live insertion/extraction permitted
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

DESCRIPTION

The 74ALVT162241 is a high-performance BiCMOS product designed for V_{CC} operation at 2.5V or 3.3V with I/O compatibility up to 5V.

This device is a 16-bit buffer that is ideal for driving bus lines. The device features four Output Enables ($1\overline{OE}$, $2OE$, $3OE$, $4\overline{OE}$), each controlling four of the 3-State outputs.

The 74ALVT162241 is designed with 30Ω series resistance in both High and Low output stages. This design reduces the line noise in applications such as memory address drivers, clock drivers and bus receivers/transmitters. The series termination resistors reduce overshoot and undershoot and are ideal for driving memory arrays.

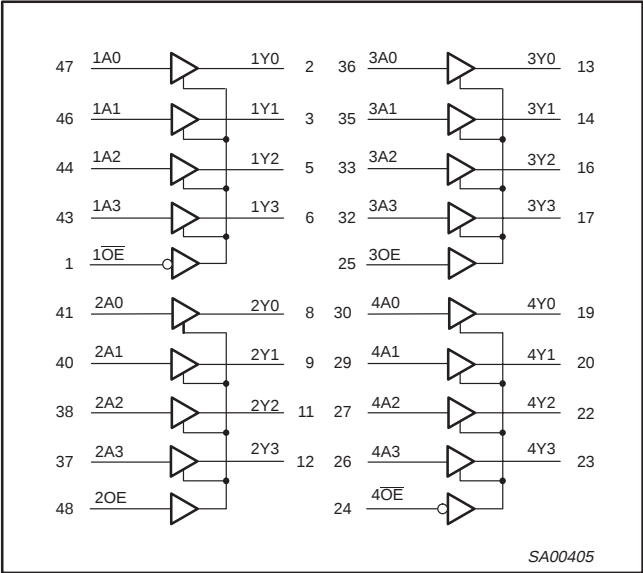
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS $T_{amb} = 25^{\circ}C$	TYPICAL		UNIT
			2.5V	3.3V	
t_{PLH} t_{PHL}	Propagation delay nAx to nYx	$C_L = 50pF$	3.1 2.3	2.2 2.0	ns
C_{IN}	Input capacitance nOE	$V_I = 0V$ or V_{CC}	3	3	pF
C_{Out}	Output pin capacitance	$V_{I/O} = 0V$ or V_{CC}	9	9	pF
I_{CCZ}	Total supply current	Outputs disabled	40	70	μA

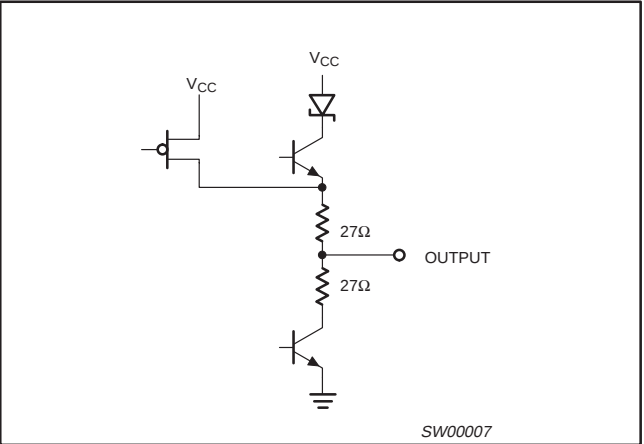
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	-40°C to +85°C	74ALVT162241 DL	AV162241 DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74ALVT162241 DGG	AV162241 DGG	SOT362-1

LOGIC SYMBOL



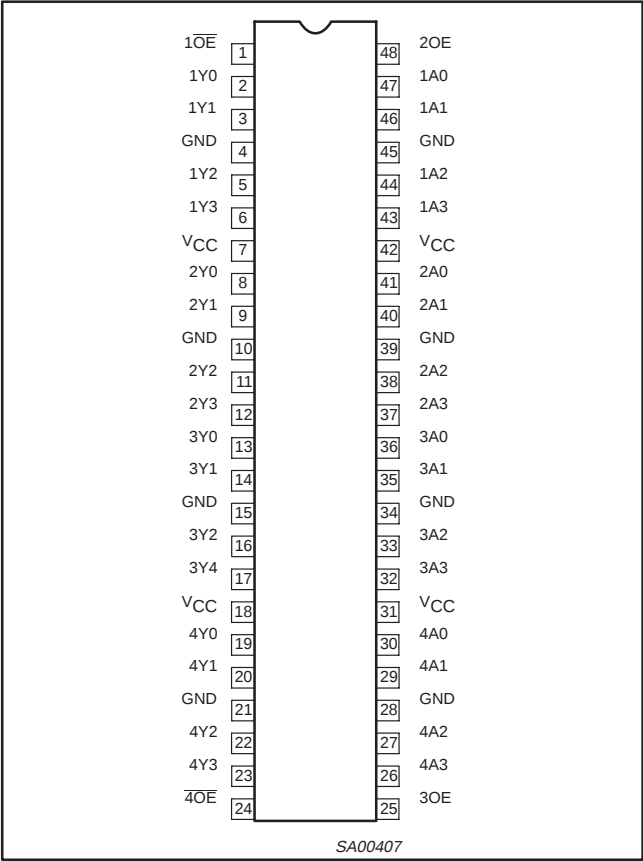
SCHEMATIC OF EACH OUTPUT



2.5V/3.3V 16-bit buffer/driver with
30Ω termination resistors (3-State)

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PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
47, 46, 44, 43, 41, 40, 38, 37, 36, 35, 33, 32, 30, 29, 27, 26	1A0-1A3 2A0-2A3 3A0-3A3 4A0-4A3	Data inputs
2, 3, 5, 6, 8, 9, 11, 12, 13, 14, 16, 17, 19, 20, 22, 23	1Y0-1Y3 2Y0-2Y3 3Y0-3Y3 4Y0-4Y3	Data outputs
1, 48, 25, 24	1OE, 2OE, 3OE, 4OE	Output enables
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	VCC	Positive supply voltage

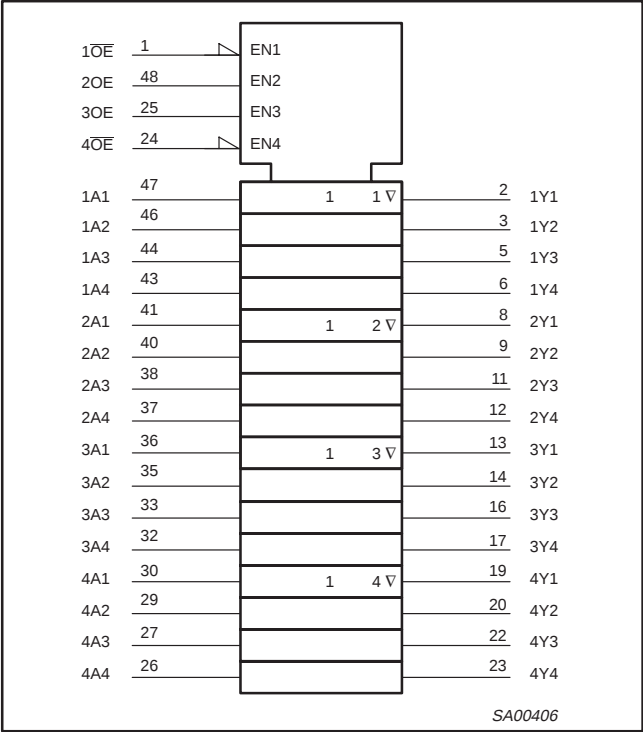
FUNCTION TABLE

Inputs		Outputs
1OE, 4OE	1Ax, 4Ax	1Yx, 4Yx
L	H	H
L	L	L
H	X	Z

Inputs		Outputs
2OE, 3OE	2Ax, 3Ax	2Yx, 3Yx
H	H	H
H	L	L
L	X	Z

H = High voltage level
L = Low voltage level
X = Don't care
Z = High Impedance "off" state

LOGIC SYMBOL (IEEE/IEC)



2.5V/3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

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ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		-0.5 to +4.6	V
I_{IK}	DC input diode current	$V_I < 0$	-50	mA
V_I	DC input voltage ³		-0.5 to +7.0	V
I_{OK}	DC output diode current	$V_O < 0$	-50	mA
V_{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
I_{OUT}	DC output current	Output in Low state	128	mA
		Output in High state	-64	
T_{stg}	Storage temperature range		-65 to +150	°C

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
- The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	2.5V RANGE LIMITS		3.3V RANGE LIMITS		UNIT
		MIN	MAX	MIN	MAX	
V_{CC}	DC supply voltage	2.3	2.7	3.0	3.6	V
V_I	Input voltage	0	5.5	0	5.5	V
V_{IH}	High-level input voltage	1.7		2.0		V
V_{IL}	Input voltage		0.7		0.8	V
I_{OH}	High-level output current		-8		-12	mA
I_{OL}	Low-level output current		12		12	mA
$\Delta t/\Delta v$	Input transition rise or fall rate; Outputs enabled		10		10	ns/V
T_{amb}	Operating free-air temperature range	-40	+85	-40	+85	°C

2.5V/3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

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DC ELECTRICAL CHARACTERISTICS (3.3V ± 0.3V RANGE)

SYMBOL	PARAMETER	TEST CONDITIONS		LIMITS			UNIT
				Temp = -40°C to +85°C			
				MIN	TYP ¹	MAX	
V _{IK}	Input clamp voltage	V _{CC} = 3.0V; I _{IK} = -18mA			-0.85	-1.2	V
V _{OH}	High-level output voltage	V _{CC} = 3.0V; I _{OH} = -12mA		2.0	2.3		V
V _{OL}	Low-level output voltage	V _{CC} = 3.0V; I _{OL} = 12mA			0.5	0.8	V
I _I	Input leakage current	V _{CC} = 3.6V; V _I = V _{CC} or GND	Control pins		0.1	±1	μA
		V _{CC} = 0 or 3.6V; V _I = 5.5V			0.1	10	μA
		V _{CC} = 3.6V; V _I = V _{CC}	Data pins ⁴		0.5	1	μA
		V _{CC} = 3.6V; V _I = 0			0.1	-5	
I _{OFF}	Off current	V _{CC} = 0V; V _I or V _O = 0 to 4.5V			0.1	±100	μA
I _{HOLD}	Bus Hold current Data inputs ⁶	V _{CC} = 3.0V; V _I = 0.8V		75	130		μA
		V _{CC} = 3.0V; V _I = 2.0V		-75	200		
		V _{CC} = 0V to 3.6V; V _{CC} = 3.6V		±500			
I _{EX}	Current into an output in the High state when V _O > V _{CC}	V _O = 5.5V; V _{CC} = 3.0V			10	125	μA
I _{PU/PD}	Power up/down 3-State output current ³	V _{CC} ≤ 1.2V; V _O = 0.5V to V _{CC} ; V _I = GND or V _{CC} OE/OE = Don't care			1	±100	μA
I _{OZH}	3-State output High current	V _{CC} = 3.6V; V _O = 3.0V; V _I = V _{IL} or V _{IH}			0.5	5	μA
I _{OZL}	3-State output Low current	V _{CC} = 3.6V; V _O = 0.5V; V _I = V _{IL} or V _{IH}			0.5	-5	μA
I _{CCH}	Quiescent supply current	V _{CC} = 3.6V; Outputs High, V _I = GND or V _{CC} , I _O = 0			0.07	0.1	mA
I _{CCL}		V _{CC} = 3.6V; Outputs Low, V _I = GND or V _{CC} , I _O = 0			3.5	7	
I _{CCZ}		V _{CC} = 3.6V; Outputs Disabled; V _I = GND or V _{CC} , I _O = 0 ⁵			0.07	0.1	
ΔI _{CC}	Additional supply current per input pin ²	V _{CC} = 3V to 3.6V; One input at V _{CC} -0.6V, Other inputs at V _{CC} or GND			0.04	0.4	mA

NOTES:

- All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
- This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.
- This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V a transition time of 100μsec is permitted. This parameter is valid for T_{amb} = 25°C only.
- Unused pins at V_{CC} or GND.
- I_{CCZ} is measured with outputs pulled up to V_{CC} or pulled down to ground.
- This is the bus hold overdrive current required to force the input to the opposite logic state.

AC CHARACTERISTICS (3.3V ± 0.3V RANGE)

GND = 0V; t_R = t_F = 2.5ns; C_L = 50pF; R_L = 500Ω; T_{amb} = -40°C to +85°C.

SYMBOL	PARAMETER	WAVEFORM	LIMITS			UNIT
			V _{CC} = 3.3V ±0.3V			
			MIN	TYP ¹	MAX	
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	1	0.5 0.5	2.2 2.0	3.6 3.0	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1.0 0.5	3.9 2.6	5.8 4.0	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	2	1.5 1.0	4.1 2.9	6.6 5.3	ns

NOTE:

- All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

2.5V/3.3V 16-bit buffer/driver with 30Ω termination resistors (3-State)

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DC ELECTRICAL CHARACTERISTICS (2.5V ± 0.2V RANGE)

SYMBOL	PARAMETER	TEST CONDITIONS		LIMITS			UNIT
				Temp = -40°C to +85°C			
				MIN	TYP ¹	MAX	
V _{IK}	Input clamp voltage	V _{CC} = 2.3V; I _{IK} = -18mA			-0.85	-1.2	V
V _{OH}	High-level output voltage	V _{CC} = 2.3V; I _{OH} = -8mA		1.7	2.1		V
V _{OL}	Low-level output voltage	V _{CC} = 2.3V; I _{OL} = 12mA			0.5	0.7	V
I _I	Input leakage current	V _{CC} = 2.7V; V _I = V _{CC} or GND	Control pins		0.1	±1	μA
		V _{CC} = 0 or 2.7V; V _I = 5.5V			0.1	10	
		V _{CC} = 2.7V; V _I = V _{CC}	Data pins ⁴		0.1	1	
		V _{CC} = 2.7V; V _I = 0			0.1	-5	
I _{OFF}	Off current	V _{CC} = 0V; V _I or V _O = 0 to 4.5V			0.1	±100	μA
I _{HOLD} ⁶	Bus Hold current	V _{CC} = 2.5V; V _I = 0.7V			90		μA
	Data inputs	V _{CC} = 2.5V; V _I = 1.7V			-70		μA
I _{EX}	Current into an output in the High state when V _O > V _{CC}	V _O = 5.5V; V _{CC} = 2.3V			10	125	μA
I _{PU/PD}	Power up/down 3-State output current ³	V _{CC} ≤ 1.2V; V _O = 0.5V to V _{CC} ; V _I = GND or V _{CC} OE/OE = Don't care			1	±100	μA
I _{OZH}	3-State output High current	V _{CC} = 2.7V; V _O = 2.3V; V _I = V _{IL} or V _{IH}			0.5	5	μA
I _{OZL}	3-State output Low current	V _{CC} = 2.7V; V _O = 0.5V; V _I = V _{IL} or V _{IH}			0.5	-5	μA
I _{CCH}	Quiescent supply current	V _{CC} = 2.7V; Outputs High, V _I = GND or V _{CC} , I _O = 0			0.04	0.1	mA
I _{CCL}		V _{CC} = 2.7V; Outputs Low, V _I = GND or V _{CC} , I _O = 0			2.3	4.5	
I _{CCZ}		V _{CC} = 2.7V; Outputs Disabled; V _I = GND or V _{CC} , I _O = 0 ⁵			0.04	0.1	
ΔI _{CC}	Additional supply current per input pin ²	V _{CC} = 2.3V to 2.7V; One input at V _{CC} -0.6V, Other inputs at V _{CC} or GND			0.01	0.4	mA

NOTES:

1. All typical values are at V_{CC} = 2.5V and T_{amb} = 25°C.
2. This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
3. This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 2.5V ± 0.2V a transition time of 100μsec is permitted. This parameter is valid for T_{amb} = 25°C only.
4. Unused pins at V_{CC} or GND.
5. I_{CCZ} is measured with outputs pulled up to V_{CC} or pulled down to ground.
6. Not guaranteed.

AC CHARACTERISTICS (2.5V ± 0.2V RANGE)

GND = 0V; t_R = t_F = 2.5ns; C_L = 50pF; R_L = 500Ω; T_{amb} = -40°C to +85°C.

SYMBOL	PARAMETER	WAVEFORM	LIMITS			UNIT
			V _{CC} = 2.5V ±0.2V			
			MIN	TYP ¹	MAX	
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	1	0.5 0.5	3.1 2.3	4.6 3.6	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1.5 1.0	4.8 3.4	7.5 6.0	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	2	1.0 0.5	4.5 3.0	8.3 6.3	ns

NOTE:

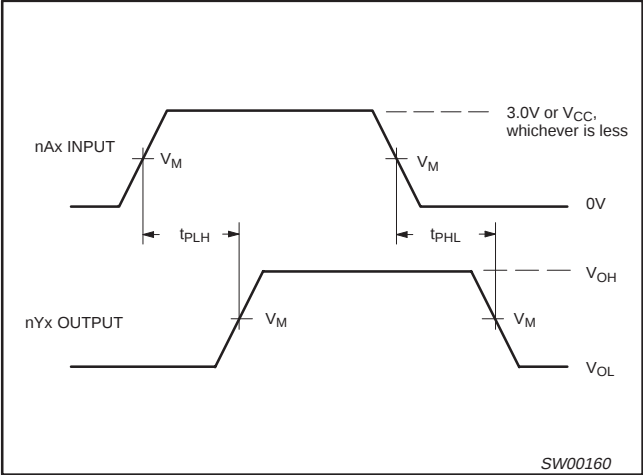
1. All typical values are at V_{CC} = 2.5V and T_{amb} = 25°C.

2.5V/3.3V 16-bit buffer/driver with
30Ω termination resistors (3-State)

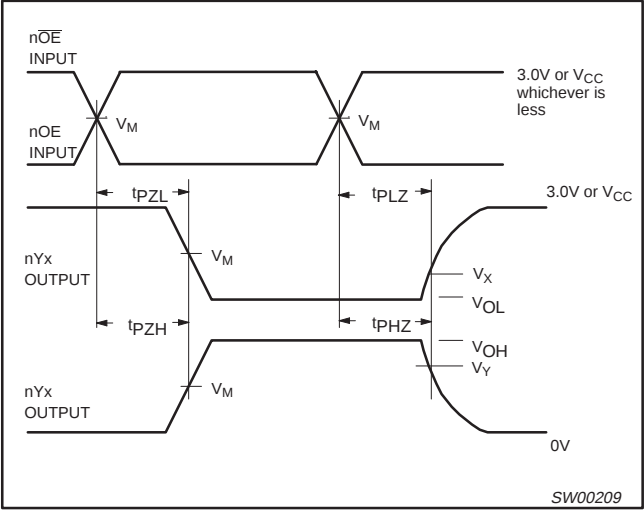
74ALVT162241

AC WAVEFORMS

$V_M = 1.5V$ at $V_{CC} \geq 3.0V$; $V_M = V_{CC}/2$ at $V_{CC} \leq 2.7V$
 $V_X = V_{OL} + 0.3V$ at $V_{CC} \geq 3.0V$; $V_X = V_{OL} + 0.15V$ at $V_{CC} \leq 2.7V$
 $V_Y = V_{OH} - 0.3V$ at $V_{CC} \geq 3.0V$; $V_Y = V_{OH} - 0.15V$ at $V_{CC} \leq 2.7V$



Waveform 1. Input (nAx) to Output (nYx) Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times

TEST CIRCUIT AND WAVEFORMS

Test Circuit for 3-State Outputs

SWITCH POSITION

TEST	SWITCH
t_{PHZ}/t_{PZH}	GND
t_{PLZ}/t_{PZL}	6V or $V_{CC} \times 2$
t_{PLH}/t_{PHL}	open

DEFINITIONS

R_L = Load resistor; see AC CHARACTERISTICS for value.

C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

$V_M = 1.5V$ or $V_{CC} / 2$, whichever is less
Input Pulse Definition

FAMILY	INPUT PULSE REQUIREMENTS				
	Amplitude	Rep. Rate	t_W	t_R	t_F
74ALVT16	3.0V or V_{CC} whichever is less	$\leq 10MHz$	500ns	$\leq 2.5ns$	$\leq 2.5ns$

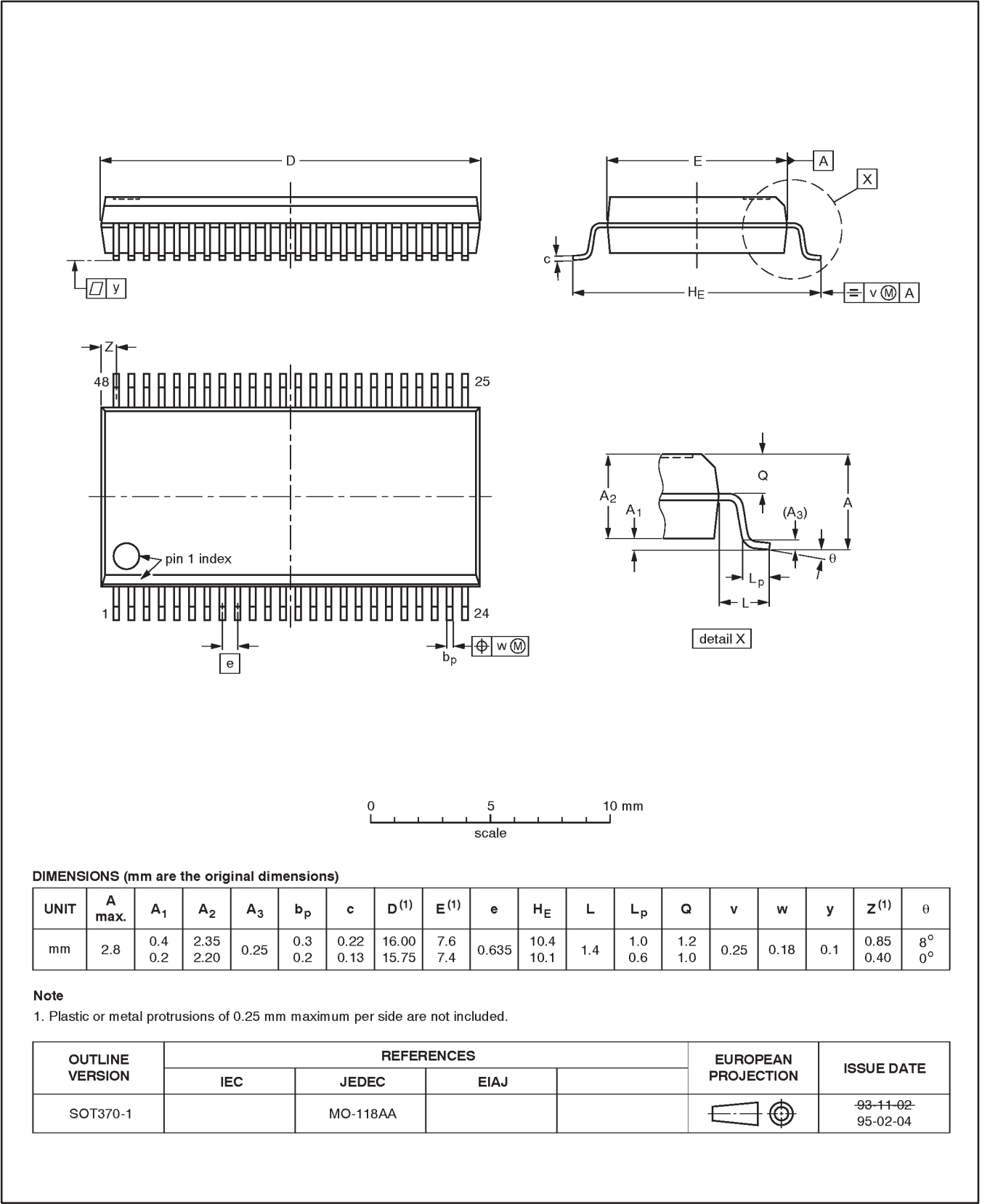
SW00162

2.5V/3.3V ALVT 16-bit buffer/driver with 30Ω termination resistors (3-State)

74ALVT162241

SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1



74ALVT162241

SOT362-1



2.5V/3.3V 16-bit buffer/driver with 30 Ω termination resistors (3-State)

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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
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[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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